

Vishay Semiconductors

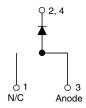
COMPLIANT

HALOGEN FREE

HEXFRED® Ultrafast Soft Recovery Diode, 8 A



D-PAK (TO-252AA)



PRODUCT SUMMARY					
Package	D-PAK (TO-252AA)				
I _{F(AV)}	8 A				
V_{R}	600 V				
V _F at I _F	1.7 V				
t _{rr} typ.	18 ns				
T _J max.	150 °C				
Diode variation	Single die				

FEATURES

- Ultrafast recovery time
- Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- · Guaranteed avalanche
- Specified at operating conditions
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21
- definitionMeets MSL level 1, per J-STD-020, LF maximum peak of
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for freewheeling, flyback, power converters, motor drives, and other applications where high speed and reduced switching losses are design requirements.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Cathode to anode voltage	V_{RRM}		600	V			
Maximum continuous forward current	I _F	T _C = 100 °C	8				
Single pulse forward current	I _{FSM}		60	Α			
Peak repetitive forward current	I _{FRM}		24				
Maximum power dissipation	P_D	T _C = 100 °C	14	W			
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to + 150	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	TEST CONDITIONS		TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ		600	-	-		
Forward voltage		I _F = 8 A	See fig. 1	-	1.4	1.7	V	
	V_{F}	I _F = 16 A		-	1.7	2.1		
		I _F = 8 A, T _J = 125 °C		-	1.4	1.7		
Maximum reverse	,	V _R = V _R rated		-	0.3	5.0		
leakage current	I _R	$T_J = 125 ^{\circ}\text{C}, V_R = 0.8 \text{x} V_R \text{rated}$		-	100	500	μA	
Junction capacitance	C _T	V _R = 200 V	See fig. 3	-	10	25	pF	
Series inductance	L _S	Measured lead to lead 5 mm from page	ckage body	-	8.0	-	nH	

Document Number: 93474 Revision: 31-Mar-11

VS-HFA08SD60S-M3

Vishay Semiconductors

HEXFRED® Ultrafast Soft Recovery Diode, 8 A



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	18	-		
Reverse recovery time	t _{rr}	T _J = 25 °C	I _F = 8 A dI _F /dt = 200 A/μs V _R = 200 V	-	37	55	ns	
		T _J = 125 °C		-	55	90		
Peak recovery current	I _{RRM}	T _J = 25 °C		-	3.5	5.0	А	
		T _J = 125 °C		-	4.5	8.0		
Poverse recovery charge	0	T _J = 25 °C		-	65	138	nC	
Reverse recovery charge	Q_{rr}	T _J = 125 °C		-	124	360	110	
Rate of fall of recovery current	dI _{(rec)M} /dt	T _J = 25 °C		-	240	-	Λ/μο	
		T _J = 125 °C		-	210	-	A/μs	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55	-	150	°C	
Thermal resistance, junction to case	R _{thJC}		-	-	3.5	°C/W	
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80	C/VV	
Weight			-	2.0	-	g	
weight			-	0.07	-	oz.	
Marking device		Case style D-PAK		HFA08	SD60S		



HEXFRED® Ultrafast Soft Recovery Diode, 8 A Vishay Semiconductors

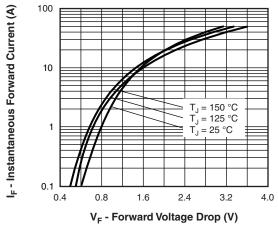


Fig. 1 - Typical Forward Voltage Drop Characteristics

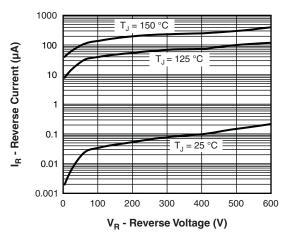


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

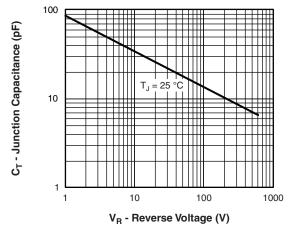


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

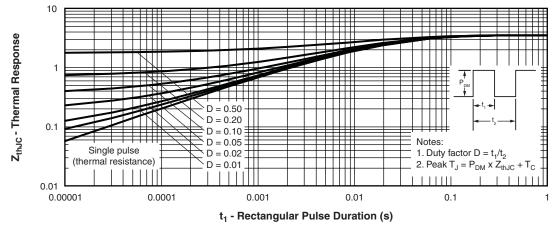


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Vishay Semiconductors

HEXFRED® Ultrafast Soft Recovery Diode, 8 A



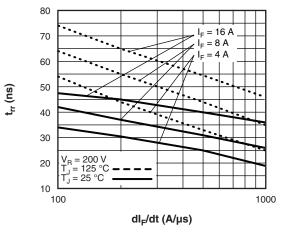


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt

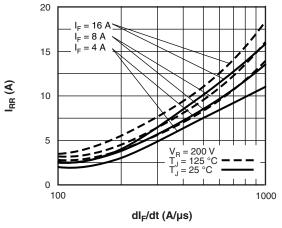


Fig. 6 - Typical Recovery Current vs. dl_F/dt

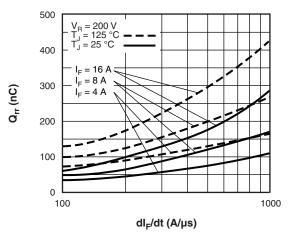


Fig. 7 - Typical Stored Charge vs. dl_F/dt

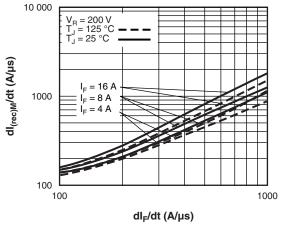


Fig. 8 - Typical $dI_{(rec)M}/dt$ vs. dI_F/dt



HEXFRED® Ultrafast Soft Recovery Diode, 8 A Vishay Semiconductors

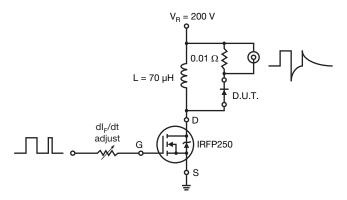
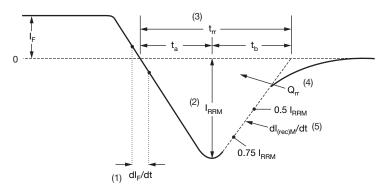


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dI_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $t_{\rm rr}$ reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) Q_{rr} area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dl_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

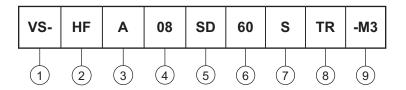
Vishay Semiconductors

HEXFRED® Ultrafast Soft Recovery Diode, 8 A



ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 HEXFRED® family
 - Electron irradiated
- Current rating (08 = 8 A)
- 5 D-PAK
- Voltage rating (60 = 600 V)
- 7 S = D-PAK
- 8 • TR = Tape and reel
 - R = Tape and reel (right oriented)
 - L = Tape and reel (left oriented)
- 9 Environmental digit:

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

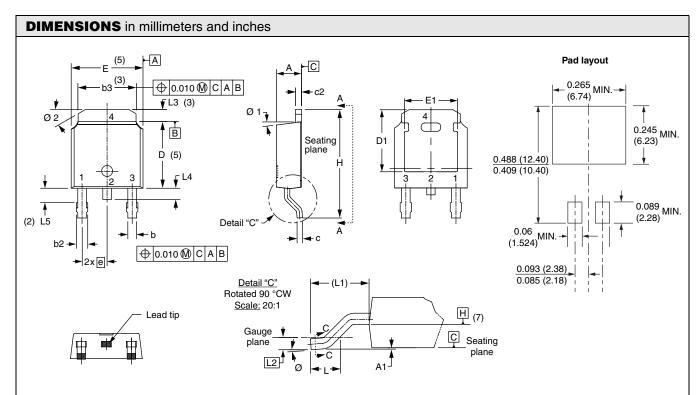
ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-HFA08SD60S-M3	75	3000	Antistatic plastic tube				
VS-HFA08SD60STR-M3	2000	2000	13" diameter reel				
VS-HFA08SD60SL-M3	3000	3000	13" diameter reel				
VS-HFA08SD60SR-M3	3000	3000	13" diameter reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95016				
Part marking information	www.vishay.com/doc?95176				
Packaging information	www.vishay.com/doc?95033				



Vishay High Power Products

D-PAK (TO-252AA)



SYMBOL	MILLIM	ETERS	INCHES		NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.18	2.39	0.086	0.094	
A1	-	0.13	-	0.005	
b	0.64	0.89	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	3
С	0.46	0.61	0.018	0.024	
c2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	5
D1	5.21	-	0.205	-	3
Е	6.35	6.73	0.250	0.265	5
E1	4.32	-	0.170	-	3

SYMBOL	MILLIM	MILLIMETERS		INCHES	
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29 BSC		0.090 BSC		
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108 REF.		
L2	0.51 BSC		0.020 BSC		
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- $^{(7)}$ Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Revision: 11-Mar-11